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Amorphous Silicon Solar Vivaldi Antenna

Oisin O’Conchubhair, Kansheng Yang, Patrick McEvoy, Senior Member, IEEE
and Max J. Ammann, Senior Member, IEEE

Abstract— An ultra-wideband solar Vivaldi antenna is proposed. Cut from amorphous silicon cells, it maintains a peak power at 4.25 V which discounts the need for lossy power management components. The wireless communications device can yield solar energy or be configured as a rectenna for dual-energy harvesting. The solar Vivaldi performs with 0.5 - 2.8 dBi gain from 0.95 - 2.45 GHz. In rectenna mode, it covers three bands for wireless energy scavenging.

Index Terms—Vivaldi, Ultra-wideband, Amorphous Silicon Solar Cell, Energy Scavenging.

I. INTRODUCTION

The number of wireless sensor networks is ever increasing and with it, the requirement to replace and dispose of discharged batteries. Consequently, devices that harvest energy from their environments are desirable [1]. Solar cell energy sources compete with antennas for surface area on the device, making it attractive to combine the technologies.

In [2], a Hydrogenated Amorphous Silicon (a-Si:H) solar cell constituted an ultra-wideband monopole antenna with a bevelled copper feed for use as a wireless sensor. Simulated results showed the 2 - 10 GHz antenna had 0 - 3 dBi gain. The average power consumption by the sensor was 29 μW, which could be supported for more than 48 hours using a 500 mF storage capacitor. In [3], a pair of a-Si:H cells were adapted to form a 3 - 10 GHz dipole antenna with a 3 dBi peak gain. The average power consumption of the sensor was 55 μW, which lasted 95 minutes using a 70 mF storage capacitor. Both [2] and [3] require lossy boost converters to convert their 0.7 V DC voltage to 3.8 V for use.

In [4], a panel of three a-Si:H solar cells constituted an aperture coupled slot antenna with 3.5 dBi gain at 2.4 GHz and 3.1 dBi gain at 5.2 GHz. While the 3.8 V output Voltages avoided lossy power management circuit components, the antenna slot resulted in a 27% reduction of the solar cells area.

Wireless energy scavenging [5] from 0.35 - 3 GHz showed 8 bands that sum to 195 MHz which could support low-power sensor devices. While scavenged power was small [6], low-powered microcontrollers (e.g. 24FJ series PIC) can maintain a deep sleep mode without data loss using 132 nW [7].

A 2.4 - 2.46 GHz Vivaldi antenna made of copper produced a 0 dBi gain to feed a rectifier [8]. With 22 μW/cm2 incident power densities, the rectenna had a 2 V output.

Fig. 1 shows a Vivaldi antenna, which for the first time, was cut from a panel of Amorphous Silicon (a-Si) solar cells. It was designed for wireless communications, with complementary solar energy harvesting, or to act as a rectenna for dual-energy harvesting. The Vivaldi cut out separated two strings of solar cells in the panel and minimised the loss of solar voltaic generation. The antenna had a directive radiation pattern and wide frequency range that included GSM and WLAN bands. With a peak power at 4.25 V, the a-Si cell could power a wireless sensor without a lossy boost converter or a voltage regulator.

Where the antenna might be applied to wireless scavenging, it would complement the loss of solar energy during hours of darkness and supplement the supply during daylight.

II. PROPOSED ANTENNA CONFIGURATIONS

A coplanar Vivaldi antenna was cut from a 0.6 W a-Si panel of ten solar cells arranged in a series of 5 pairs of parallel connected cells [9]. The 400 nm thick a-Si layer of each cell was 71 × 18 mm and separated from other cells by a 2 mm gap [10]. Each cell had 7 silver electrodes on the front contact. The electrodes are 0.5 × 16.5 mm and separated by 9.5 mm. Rear contacts, 19.9 × 146 mm, provided parallel connections between cells and were isolated from adjacent contacts by a 0.1 mm gap. The low-cost flexible panels were manufactured for one of many different power configurations and the layout enabled various antenna shapes. End edge contacts on the panel were made from tin-coated copper plate. The entire panel was encapsulated by flexible polyimide layer.

Equation (1) describes the exponential curve of the Vivaldi antenna where \( x_0 \) was the first point of the curve and \( gr \) was the rate of change in the curve [11].

\[
    x = x_0 \ast \exp(gr \ast t) \text{ for } y_{min} < t < y_{max} \quad (1)
\]

Fig. 1. Solar Vivaldi antenna (left) and rear-side transmission line (right)
The antenna was fed with a 50 Ω microstrip transmission line printed on the FR-4 substrate used to support the solar panel. The transmission line was terminated in a microstrip to slot-line transition between a quarter wave radial stub and quarter wave circular slot. Table I summarises preliminary simulations with CST Microwave Studio that optimised the stub length to support a band lower than GSM-900 while minimising a circular slot in a copper layer. Having built the simulation model to include the entire solar panel and antenna, final dimensions were optimised for the Vivaldi slot.

The simulated solar Vivaldi antenna was designed with the minimal amount (3.6%) of silicon removed. The slot location was varied to 35 mm from the symmetrical centre between the cells with a loss of 5% of a-Si. While a 5 mm offset had minimal impact, the 35 mm offset reduced the bandwidth by 294 MHz to remove the 900 GSM band.

The silicon-optimised features were copied in double-sided copper on an FR-4 substrate for performance benchmark.

### III. RESULTS AND DISCUSSION

The $S_{11}$ results and simulated efficiencies are summarised in Table II and plot comparisons are shown in Fig. 2. The gain data for the measured and simulated antennas is shown in Table III. A comparison between measured boresight gain for the solar and copper Vivaldis are shown in Fig. 3.

The $S_{11}$ response, the efficiency and the gain values are lower for the solar antenna when compared to the copper antenna suggesting increased losses. Simulated results show that some of this loss is due to current flow along the edges of intersections between the solar cells as shown in Fig. 4.

The X-Z beamwidth is narrower than the X-Y beamwidth for all frequencies. In addition the beamwidths narrow as frequency increases with the lower frequency being omnidirectional in the X-Y plane. Radiations plots for the antenna at 950 MHz, 1.87 GHz and 2.45 GHz are shown in Fig. 5, Fig. 6 and Fig. 7 respectively.

### IV. SOLAR CELL POWER GENERATION

Solar measurements were carried out using a 1450 Lux light source positioned 960 mm from the solar panel. The solar Vivaldi antenna has been compared to an intact solar panel. The intact solar panel was also supported on an FR 4 substrate to prevent any differences in thermal properties. The outline of the Vivaldi slot is shown imposed on the intact solar panel in Fig. 8 with the removed sections of silicon marked in green.

As the Vivaldi slot was centred between adjacent solar cells it removes equal amounts of silicon from each cell and splits the panel into two strings of series connected cells. Section A removed 14.40% of the silicon from the affected cell. Section

### TABLE I

<table>
<thead>
<tr>
<th>Stub Length</th>
<th>Lower -10 dB</th>
<th>Cell Area Removed (%)</th>
<th>$S_{11}$ at 0.95 GHz (dB)</th>
<th>$S_{11}$ at 1.87 GHz (dB)</th>
<th>$S_{11}$ at 2.45 GHz (dB)</th>
</tr>
</thead>
<tbody>
<tr>
<td>10 mm</td>
<td>0.98</td>
<td>2.29</td>
<td>-8.9</td>
<td>-22.4</td>
<td>-10.2</td>
</tr>
<tr>
<td>12 mm</td>
<td>0.84</td>
<td>3.49</td>
<td>-16.8</td>
<td>-21.1</td>
<td>-9.8</td>
</tr>
<tr>
<td>14 mm</td>
<td>0.74</td>
<td>4.93</td>
<td>-28.4</td>
<td>-17.5</td>
<td>-9.8</td>
</tr>
</tbody>
</table>

### TABLE II

<table>
<thead>
<tr>
<th>Antenna</th>
<th>Min $S_{11}$ (GHz)</th>
<th>Bandwidth (%)</th>
<th>0.95 GHz (dB)</th>
<th>1.87 GHz (dB)</th>
<th>2.45 GHz (dB)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Meas a-Si</td>
<td>0.938</td>
<td>127</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
</tr>
<tr>
<td>Sim a-Si</td>
<td>0.921</td>
<td>123</td>
<td>84%</td>
<td>78%</td>
<td>70%</td>
</tr>
<tr>
<td>Meas Cu</td>
<td>0.576</td>
<td>159</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
</tr>
<tr>
<td>Sim Cu</td>
<td>0.752</td>
<td>148</td>
<td>95%</td>
<td>89%</td>
<td>77%</td>
</tr>
</tbody>
</table>

### TABLE III

<table>
<thead>
<tr>
<th>Frequency (GHz)</th>
<th>Measured Solar (dBi)</th>
<th>Measured Copper (dBi)</th>
<th>Simulated Solar (dBi)</th>
<th>Simulated Copper (dBi)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.95</td>
<td>0.04</td>
<td>0.31</td>
<td>1.05</td>
<td>0.92</td>
</tr>
<tr>
<td>1.87</td>
<td>3.91</td>
<td>4.2</td>
<td>3.84</td>
<td>4.66</td>
</tr>
<tr>
<td>2.45</td>
<td>5.28</td>
<td>4.52</td>
<td>5.46</td>
<td>5.19</td>
</tr>
</tbody>
</table>
B removed 1.71% and section C was 1.89%. This resulted in a loss of 3.6% of the total available silicon. As section A was the largest cut in a single cell, thereby setting the current limit of that string.

The maximum power point of the full solar cell was 51.7 mW (4.25 V × 12.2 mA). With the strings reconnected, the maximum power point of the solar Vivaldi antenna was 27.4 mW (2.67 V × 10.3 mA). This was a 15.57% decrease in current at the maximum power point which was proportionate with the percentage of material removed. Measured solar power outputs are shown in Fig. 9.

If this antenna was to go into production, the solar cell could be redesigned to ensure each cell in the series had an equal volume of a-Si. In [12], a custom a-Si:H solar cell was manufactured to conform to the shape required for a slot antenna. Laser etching of the layers of the solar cell in a certain pattern make it possible to achieve the desired shape without requiring modification to existing production equipment [13]. This would optimize the cells to suit the available space of the solar Vivaldi antenna and improve the output power of the final solar panel.

V. ENERGY SCAVENGING POTENTIAL

An 8-stage Villard cascade voltage multiplier circuit was designed to test the energy scavenging potential of the solar Vivaldi. The Villard cascade configuration is shown in Fig. 10 where the C1 = 100 pF, R1 = 10M Ω and D1 is a HSMS-268C-TR1G. A 100 pF storage capacitor and 10M Ω load were chosen to ensure quick charge and discharge during testing.

A Hewlett Packard 8648C signal generator with a Mini-Circuits ZFL-2500 31 dB amplifier and a horn antenna located 1 m from the solar Vivaldi was used for testing. The system was measured between the signal generator and the horn, giving a gain of 31 dB at 950 MHz, 32 dB at 1.87 GHz and 31 dB at 2.45 GHz. The horn antenna gain was 9.6 dBi at 950 MHz, 10.8 dBi at 1.87 GHz and 12.4 dBi at 2.45 GHz.

The voltage multiplier output was measured in an anechoic chamber to minimise reflection and the inverse-square law was used to calculate the power density (P_D) at the receive antenna, results are shown in Table IV.

It is clear that with an incident power density of 1.6 μW/cm² at 950 MHz, 2.7 μW/cm² at 1.87 GHz or 17.4 μW/cm² at 2.45 GHz the rectenna can exceed the 1.8 V
and 132 nW required for a microcontroller [7] to maintain deep sleep mode.

VI. CONCLUSIONS

An ultra-wideband (0.938 - 2.45 GHz) Vivaldi antenna made from an amorphous silicon solar cell was reported for the first time. The wide bandwidth included GSM and WLAN channels to support devices used in remote locations. At all measured frequencies, the beamwidth exceeded 110° in at least one plane to order to improve the probability of suitable orientations for RF transmission, solar generation and wireless energy scavenging.

Simulated and measured results for the solar Vivaldi showed that the narrow spacing between the rear contacts of each solar cell is sufficiently smaller than a wavelength to ensure minimal impact. Simulated results suggest the solar antenna is around 10% less efficient compared to an equivalent copper. Measured gain is 1 dB less at 950 MHz when compared to the equivalent copper antenna, which suggests there were increased losses due to the silicon, encapsulating material and current flow along intersections between solar cells. The measured gain values are ~1 dB higher than other ultra wideband solar antennas.

Solar measurements have shown that the removal of silicon to create the solar Vivaldi reduced the power output of the solar cell. Measured maximum power point for the solar Vivaldi is 47% lower than that of an intact panel. This can be improved by manufacturing the solar panel with the Vivaldi slot built in and equal silicon area in each cell.

Calculations of energy scavenging performance showed that while power received is low there is potential to maintain a microcontroller in deep sleep mode while energy is stored for use later.

ACKNOWLEDGMENT

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